

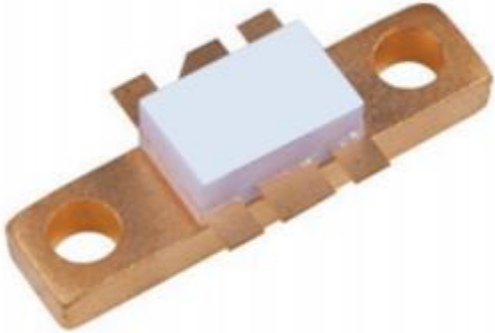
RF Silicon Mosfet

5W 500MHz 28V Single-Ended

D2015UK

Features:

- Simplified Amplifier Design
- Suitable for Broad Band Applications
- Low C_{rss}
- Simple Bias Circuits
- Low Noise
- High Gain – 13dB Minimum
- RoHS Compliant



Description:

Single-Ended RF Silicon Mosfet. 5W at 500MHz, 28V

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ unless otherwise noted)

P_D	Power Dissipation	29W
BV_{DSS}	Drain – Source Breakdown Voltage	65V
BV_{GSS}	Gate – Source Breakdown Voltage	$\pm 20\text{V}$
$I_D(\text{sat})$	Drain Current	2A
T_{stg}	Storage Temperature	-65 to +150°C
T_j	Maximum Operating Junction Temperature	200°C

Thermal Properties

SYMBOL	PARAMETER	MAX	UNITS
$R_{\theta JC}$	Thermal Resistance, Junction to Case	6.0	°C/W

Electrical Specifications

Electrical Characteristics (T_A = 25° C unless otherwise noted)

SYMBOL	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0V, I _D = 10mA	65			V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 28V, V _{GS} = 0V			2	mA
I _{GSS}	Gate leakage Current	V _{GS} = 20V, V _{DS} = 0V			1	μA
V _{GS(th)}	Gate Threshold Voltage	I _D = 10mA, V _{DS} = V _{GS}	1		7	V
g _{fs}	Forward Transconductance	V _{DS} = 10V, I _D = 0.4A	0.36			S
G _{PS}	Common Source Power Gain	P _O = 5W	13			dB
η	Drain Efficiency	V _{DS} = 28V, I _{DQ} = 0.2A	40			%
VSWR ⁽¹⁾	Load Mismatch Tolerance	f = 500MHz	20:1			-
C _{iss} ⁽¹⁾	Input Capacitance	V _{DS} = 28V, V _{GS} = -5V f = 1MHz			24	pF
C _{oss} ⁽¹⁾	Output Capacitance	V _{DS} = 28V, V _{GS} = 0V f = 1MHz			11	pF
C _{rss} ⁽¹⁾	Reverse Transfer Capacitance	V _{DS} = 28V, V _{GS} = 0V f = 1MHz			1	pF

Notes:

- (1) By design only, not a production test

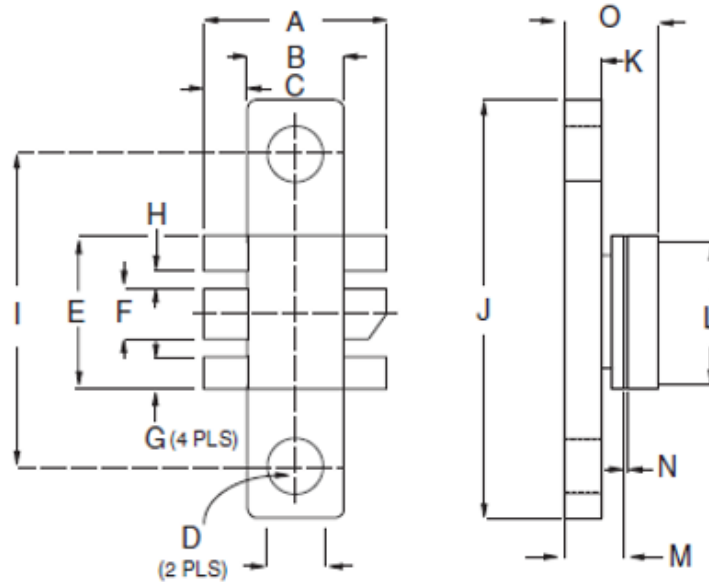
HAZARDOUS MATERIAL WARNING

The ceramic portion of the device between leads and metal flange is beryllium oxide. Beryllium oxide dust is highly toxic and care must be taken during handling and mounting to avoid damage to this area.

THESE DEVICES MUST NEVER BE THROWN AWAY WITH GENERAL INDUSTRIAL OR DOMESTIC WASTE

Packaging

Mechanical Data



SOT171

Top View

- Pin 1 - Source
- Pin 2 - Source
- Pin 3 - Gate
- Pin 4 - Drain
- Pin 5 - Source
- Pin 6 - Source

DIM	mm	Tol.	Inches	Tol.
A	10.92	0.38	0.430	0.015
B	5.84	0.13	0.230	0.005
C	2.54	0.13	0.100	0.005
D	3.30 dia	1.27	0.130 dia	0.050
E	9.14	0.13	0.360	0.005
F	3.05	0.13	0.120	0.005
G	2.01	0.13	0.079	0.005
H	1.07	0.13	0.042	0.005
I	18.42	0.13	0.725	0.005
J	24.77	0.13	0.975	0.005
K	2.79	0.13	0.110	0.005
L	9.14	0.13	0.360	0.005
M	4.22	0.25	0.166	0.010
N	0.13	0.05	0.005	0.002
O	7.37	MAX	0.290	MAX

Revision Control

ISSUE	CHANGE DESCRIPTION	APPROVAL	DATE
1	First issue	P.Smith	17-08-2001
2	Corrected dimension tolerances	P.Smith	25-06-2020